# **Low Voltage Dual 1:10 Differential ECL/PECL Clock Fanout Buffer**

The Motorola MC100ES6220 is a bipolar monolithic differential clock fanout buffer. Designed for most demanding clock distribution systems, the MC100ES6220 supports various applications that require the distribution of precisely aligned differential clock signals. Using SiGe technology and a fully differential architecture, the device offers very low skew outputs and superior digital signal characteristics. Target applications for this clock driver are high performance clock distribution in computing, networking and telecommunication systems.

#### **Features**

- Two independent 1:10 differential clock fanout buffers
- 130 ps maximum device skew
- SiGe technology
- Supports DC to 1GHz operation of clock or data signals
- ECL/PECL compatible differential clock outputs
- ECL/PECL compatible differential clock inputs
- Single 3.3V, -3.3V, 2.5V or -2.5V supply
- Standard 52 lead LQFP package with exposed pad for enhanced thermal characteristics
- Supports industrial temperature range
- Pin and function compatible to the MC100EP220

# **Functional Description**

The MC100ES6220 is designed for low skew clock distribution systems and supports clock frequencies up to 1 GHz. The device consists of two independent clock fanout buffers. The CLKA and CLKB inputs can be driven by ECL or PECL compatible signals. The input signal of each clock buffer is distributed to 10 identical, differential ECL/PECL outputs. If VBB is connected to the CLKA or CLKB input and bypassed to GND by a 10 nF capacitor, the MC100ES6220 can be driven by single-ended ECL/PECL signals utilizing the VBB bias voltage output.

In order to meet the tight skew specification of the device, both outputs of a differential output pair should be terminated, even if only one output is used. In the case where not all ten outputs are used, the output pairs on the same package side as the parts being used on that side should be terminated.

The MC100ES6220 can be operated from a single 3.3V or 2.5V supply. As most other ECL compatible devices, the MC100ES6220 supports positive (PECL) and negative (ECL) supplies. The MC100ES6220 is pin and function compatible to the MC100EP220.

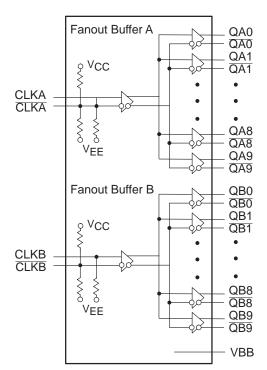
# MC100ES6220

**LOW VOLTAGE DUAL 1:10 DIFFERENTIAL ECL/PECL CLOCK FANOUT BUFFER** 



**TB SUFFIX** 52-LEAD LQFP PACKAGE **EXPOSED PAD CASE 1336A** 





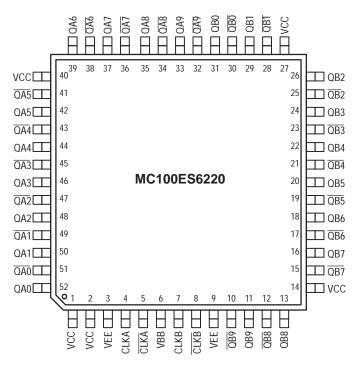


Figure 1. MC100ES6220 Logic Diagram

Figure 2. 52-Lead Package Pinout (Top View)

Table 1. Pin configuration

Pin	I/O	Туре	Function
CLKA, CLKA	Input	ECL/PECL	Differential reference clock signal input for fanout buffer A
CLKB, CLKB	Input	ECL/PECL	Differential reference clock signal input for fanout buffer B
QA[0-9], QA[0-9]	Output	ECL/PECL	Differential clock outputs of fanout buffer A
QB[0-9], QB[0-9]	Output	ECL/PECL	Differential clock outputs of fanout buffer B
VEEa	Supply		Negative power supply
VCC	Supply		Positive power supply. All V <sub>CC</sub> pins must be connected to the positive power supply for correct DC and AC operation.
VBB	Output	DC	Reference voltage output for single ended ECL or PECL operation

a. In ECL mode (negative power supply mode), VEE is either -3.3V or -2.5V and VCC is connected to GND (0V). In PECL mode (positive power supply mode), VEE is connected to GND (0V) and VCC is either +3.3V or +2.5V. In both modes, the input and output levels are referenced to the most positive supply (VCC).

Table 2. Absolute Maximum Ratings<sup>a</sup>

Symbol	Characteristics	Min	Max	Unit	Condition
Vcc	Supply Voltage	-0.3	3.6	V	
VIN	DC Input Voltage	-0.3	V <sub>CC</sub> + 0.3	V	
Vout	DC Output Voltage	-0.3	V <sub>CC</sub> + 0.3	V	
I <sub>IN</sub>	DC Input Current		±20	mA	
lout	DC Output Current		±50	mA	
TS	Storage temperature	-65	125	°C	
T <sub>FUNC</sub>	Functional temperature range	$T_A = -40$	T <sub>J</sub> = +110	°C	

Absolute maximum continuous ratings are those maximum values beyond which damage to the device may occur. Exposure to these
conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation at absolute-maximum-rated
conditions is not implied.

**Table 3. General Specifications** 

Symbol	Characteristics	Min	Тур	Max	Unit	Condition
VTT	Output termination voltage		V <sub>CC</sub> -2 <sup>a</sup>		V	
MM	ESD Protection (Machine model)	175			V	
HBM	ESD Protection (Human body model)	2000			V	
CDM	ESD Protection (Charged device model	TBD			V	
LU	Latch-up immunity	200			mA	
C <sub>IN</sub>	N Input Capacitance		4.0		pF	Inputs
θJA ,θJC θJB	Thermal resistance (junction-to-ambient, junction-to-board, junction-to-case)	See Table 8, Thermal Resistance, on page 7		°C/W		
ТЈ	Operating junction temperature <sup>b</sup> (continuous operation) MTBF = 9.1 years	0		110	°C	

- a. Output termination voltage  $V_{TT} = 0V$  for  $V_{CC} = 2.5V$  operation is supported but the power consumption of the device will increase.
- b. Operating junction temperature impacts device life time. Maximum continuous operating junction temperature should be selected according to the application life time requirements (See application note AN1545 for more information). The device AC and DC parameters are specified up to 110°C junction temperature allowing the MC100ES6220 to be used in applications requiring industrial temperature range. It is recommended that users of the MC100ES6220 employ thermal modeling analysis to assist in applying the junction temperature specifications to their particular application.

Table 4. PECL DC Characteristics ( $V_{CC} = 2.5V \pm 5\%$  or  $V_{CC} = 3.3V \pm 5\%$ ,  $V_{EE} = GND$ ,  $T_J = 0^{\circ}C$  to +110°C)

Symbol	Characteristics	Min	Тур	Max	Unit	Condition	
Clock input pair CLKA, CLKA, CLKB (PECL differential signals)							
VPP	Differential input voltage <sup>a</sup>	0.1		1.3	V	Differential operation	
VCMR	Differential cross point voltageb	1.0		V <sub>CC</sub> - 0.3	V	Differential operation	
I <sub>IN</sub>	Input Current <sup>a</sup>			±150	μΑ	$V_{IN} = V_{IL}$ or $V_{IN} = V_{IH}$	
Clock input	s (PECL single ended signals)						
V <sub>IH</sub>	Input Voltage High	V <sub>CC</sub> -1.165		V <sub>CC</sub> -0.880	V		
V <sub>IL</sub>	Input Voltage Low	V <sub>CC</sub> -1.810		V <sub>CC</sub> -1.475	V		
I <sub>IN</sub>	Input Current <sup>C</sup>			±150	μΑ	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IN</sub> = V <sub>IH</sub>	
PECL clock outputs (QA0-A9, QA0-A9, QB0-B9, QB0-B9)							
Vон	Output High Voltage	V <sub>CC</sub> -1.1	V <sub>CC</sub> -1.005	V <sub>CC</sub> -0.7	V	I <sub>OH</sub> = -30 mA <sup>d</sup>	
V <sub>OL</sub>	Output Low Voltage	V <sub>CC</sub> -1.9	V <sub>CC</sub> -1.705	V <sub>CC</sub> -1.4	V	I <sub>OL</sub> = -5 mAd	
Supply current and V <sub>BB</sub>							
lEE <sup>e</sup>	Maximum Quiescent Supply Current without output termination current		80	130	mA	V <sub>EE</sub> pins	
V <sub>BB</sub>	Output reference voltage	V <sub>CC</sub> - 1.42		V <sub>CC</sub> - 1.20	V	I <sub>BB</sub> = 0.3 mA	

- a. VPP (DC) is the minimum differential input voltage swing required to maintain device functionality.
- b. V<sub>CMR</sub> (DC) is the crosspoint of the differential input signal. Functional operation is obtained when the crosspoint is within the V<sub>CMR</sub> (DC) range and the input swing lies within the V<sub>PP</sub> (DC) specification.
- c. Input have internal pullup/pulldown resistors which affect the input current.
- d. Termination  $50\Omega$  to V<sub>TT</sub>.
- e.  $I_{CC}$  calculation:  $I_{CC}$  = (number of differential output used) x ( $I_{OH}$  +  $I_{OL}$ ) +  $I_{EE}$

 $I_{CC}$  = (number of differential output used) x ( $V_{OH} - V_{TT}$ )÷ $R_{load}$  + ( $V_{OL} - V_{TT}$ )÷ $R_{load}$  +  $I_{EE}$ .

Table 5. ECL DC Characteristics (VEE = -2.5V  $\pm$  5% or VEE = -3.3V  $\pm$  5%, VCC = GND, TJ = 0°C to +110°C)

Out of the state o							
Symbol	Characteristics	Min	Тур	Max	Unit	Condition	
Clock input	Clock input pair CLKA, CLKB, CLKB (ECL differential signals)						
VPP	Differential input voltage <sup>a</sup>	0.1		1.3	V	Differential operation	
VCMR	Differential cross point voltage <sup>b</sup>	V <sub>EE</sub> + 1.0		-0.3	V	Differential operation	
I <sub>IN</sub>	Input Current <sup>a</sup>			±150	μΑ	$V_{IN} = V_{IL}$ or $V_{IN} = V_{IH}$	
Clock input	s (ECL single ended signals)						
VIH	Input Voltage High	-1.165		-0.880	V		
VIL	Input Voltage Low	-1.810		-1.475	V		
I <sub>IN</sub>	Input Current <sup>C</sup>			±150	μΑ	$V_{IN} = V_{IL}$ or $V_{IN} = V_{IH}$	
ECL clock	outputs (QA0-A9, QA0-A9, QB0-B9, QB0-B9)						
Vон	Output High Voltage	-1.1	-1.005	-0.7	V	I <sub>OH</sub> = -30 mA <sup>d</sup>	
VOL	Output Low Voltage	-1.9	-1.705	-1.4	V	$I_{OL} = -5 \text{ mAd}$	
Supply current and V <sub>BB</sub>							
IEEe	Maximum Quiescent Supply Current without output termination current		80	130	mA	V <sub>EE</sub> pins	
V <sub>BB</sub>	Output reference voltage	-1.42		-1.20	V	I <sub>BB</sub> = 0.3 mA	

- a. VPP (DC) is the minimum differential input voltage swing required to maintain device functionality.
- b. V<sub>CMR</sub> (DC) is the crosspoint of the differential input signal. Functional operation is obtained when the crosspoint is within the V<sub>CMR</sub> (DC) range and the input swing lies within the V<sub>PP</sub> (DC) specification.
- c. Input have internal pullup/pulldown resistors which affect the input current.
- d. Termination  $50\Omega$  to V<sub>TT</sub>.
- e. I<sub>CC</sub> calculation: I<sub>CC</sub> = (number of differential output used) x (I<sub>OH</sub> + I<sub>OL</sub>) + I<sub>EE</sub>

  I<sub>CC</sub> = (number of differential output used) x (V<sub>OH</sub> V<sub>TT</sub>)÷R<sub>load</sub> + (V<sub>OL</sub> V<sub>TT</sub>)÷R<sub>load</sub> + I<sub>EE</sub>.

Table 6. AC Characteristics (ECL:  $V_{EE}$  = -3.3V  $\pm$  5% or  $V_{EE}$  = -2.5V  $\pm$  5%,  $V_{CC}$  = GND) or (PECL:  $V_{CC}$  = 3.3V  $\pm$  5% or  $V_{CC}$  = 2.5V  $\pm$  5%,  $V_{EE}$  = GND,  $T_J$  = 0°C to +110°C)<sup>a</sup>

Symbol	Characteristics	Min	Тур	Max	Unit	Condition
Clock input	t pair CLKA, CLKA, CLKB, CLKB (PECL or ECL differen					
V <sub>PP</sub>	Differential input voltageb (peak-to-peak)	0.3		1.3	V	
VCMR	Differential input crosspoint voltage <sup>C</sup> PEC	I		V <sub>CC</sub> -0.3 -0.3V	V	
f <sub>CLK</sub>	Input Frequency	0		1000	MHz	Differential
PECL/ECL	clock outputs (QA0-A9, QA0-A9, QB0-B9, QB0-B9)					
t <sub>PD</sub>	Propagation Delay CLKx to Qx0-9	285		550	ps	Differential
VO(P-P)	Differential output voltage (peak-to-peak)	400	600		mV	
tsk(O)	Output-to-output skew		60	130	ps	Differential
t <sub>sk(PP)</sub>	Output-to-output skew (part-to-part)			200	ps	Differential
tJIT(CC)	Output cycle-to-cycle jitter			TBD	ps	
<sup>t</sup> SK(P)	Output pulse skew <sup>d</sup>			35	ps	
DCO	Output Duty Cycle fREF < 0.1 GF fREF < 1.0 GF		50 50	50.35 53.5	% %	DC <sub>REF</sub> = 50% DC <sub>REF</sub> = 50%
t <sub>r</sub> , t <sub>f</sub>	Output Rise/Fall Time	50		350	ps	20% to 80%

- a. AC characteristics apply for parallel output termination of  $50\Omega$  to V<sub>TT</sub>.
- V<sub>PP</sub> (AC) is the minimum differential ECL/PECL input voltage swing required to maintain AC characteristics including tpd and device-to-device skew.
- c. V<sub>CMR</sub> (AC) is the crosspoint of the differential ECL/PECL input signal. Normal AC operation is obtained when the crosspoint is within the V<sub>CMR</sub> (AC) range and the input swing lies within the V<sub>PP</sub> (AC) specification. Violation of V<sub>CMR</sub> (AC) or V<sub>PP</sub> (AC) impacts the device propagation delay, device and part-to-part skew.
- d. Output pulse skew is the absolute difference of the propagation delay times:  $|t_{pLH} t_{pHL}|$ .

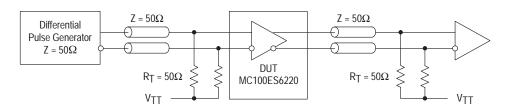


Figure 3. MC100ES6220 AC test reference

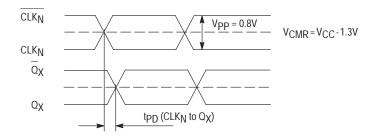


Figure 4. MC100ES6220 AC reference measurement waveform

### **APPLICATIONS INFORMATION**

# Understanding the junction temperature range of the MC100ES6220

To make the optimum use of high clock frequency and low skew capabilities of the MC100ES6220, the MC100ES6220 is specified, characterized and tested for the junction temperature range of T<sub>J</sub>=0°C to +110°C. Because the exact thermal performance depends on the PCB type, design, thermal management and natural or forced air convection, the junction temperature provides an exact way to correlate the application specific conditions to the published performance data of this datasheet. The correlation of the junction temperature range to the application ambient temperature range and vice versa can be done by calculation:

$$T_J = T_A + R_{thja} \cdot P_{tot}$$

Assuming a thermal resistance (junction to ambient) of 17 °C/W (2s2p board, 200 ft/min airflow, see Table 8 on page 7) and a typical power consumption of 1049 mW (all outputs terminated 50 ohms to VTT, VCC=3.3V, frequency independent), the junction temperature of the MC100ES6220 is approximately TA + 18 °C, and the minimum ambient temperature in this example case calculates to -18 °C (the maximum ambient temperature is 92 °C. See Table 7). Exceeding the minimum junction temperature specification of the MC100ES6220 does not have a significant impact on the device functionality. However, the continuous use the MC100ES6220 at high ambient temperatures requires thermal management to not exceed the specified maximum junction temperature. Please see the application note AN1545 for a power consumption calculation guideline.

Table 7. Ambient temperature ranges ( $P_{tot} = 1049 \text{mW}$ )

R <sub>thja</sub> (2s2p b	T <sub>A, min</sub> a	T <sub>A, max</sub>	
Natural convection	20 °C/W	–21 °C	89 °C
100 ft/min	18 °C/W	−19 °C	91 °C
200 ft/min	17 °C/W	−18 °C	92 °C
400 ft/min	16 °C/W	−17 °C	93 °C
800 ft/min	15 °C/W	−16 °C	94 °C

#### **Maintaining Lowest Device Skew**

The MC100ES6220 guarantees low output-to-output bank skew of 100 ps and a part-to-part skew of max. 200 ps. To ensure low skew clock signals in the application, both outputs of any differential output pair need to be terminated identically, even if only one output is used. When fewer than all nine output pairs are used, identical termination of all output pairs within the output bank is recommended. This will reduce the device power consumption while maintaining minimum output skew.

## **Power Supply Bypassing**

The MC100ES6220 is a mixed analog/digital product. The differential architecture of the MC100ES6220 supports low noise signal operation at high frequencies. In order to maintain its superior signal quality, all V<sub>CC</sub> pins should be bypassed by high-frequency ceramic capacitors connected to GND. If the spectral frequencies of the internally generated switching noise on the supply pins cross the series resonant point of an individual bypass capacitor, its overall impedance begins to look inductive and thus increases with increasing frequency. The parallel capacitor combination shown ensures that a low impedance path to ground exists for frequencies well above the noise bandwidth.

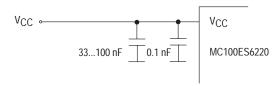


Figure 5. V<sub>CC</sub> Power Supply Bypass

### **APPLICATIONS INFORMATION**

# Using the thermally enhanced package of the MC100ES6220

The MC100ES6220 uses a thermally enhanced exposed pad (EP) 52 lead LQFP package. The package is molded so that the leadframe is exposed at the surface of the package bottom side. The exposed metal pad will provide the low thermal impedance that supports the power consumption of the MC100ES6220 high-speed bipolar integrated circuit and eases the power management task for the system design. A thermal land pattern on the printed circuit board and thermal vias are recommended in order to take advantage of the enhanced thermal capabilities of the MC100ES6220. Direct soldering of the exposed pad to the thermal land will provide an efficient thermal path. In multilayer board designs, thermal vias thermally connect the exposed pad to internal copper planes. Number of vias, spacing, via diameters and land pattern design depend on the application and the amount of heat to be removed from the package. A nine thermal via array, arranged in a 3 x 3 array and using a 1.2 mm pitch in the center of the thermal land is a requirement for MC100ES6220 applications on multi-layer boards. The recommended thermal land design comprises a 3 x 3 thermal via array as shown in Figure 6 "Recommended thermal land pattern", providing an efficient heat removal path.

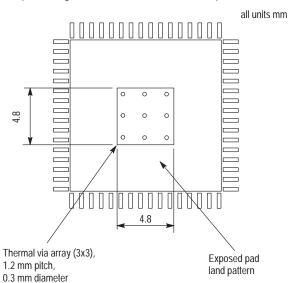


Figure 6. Recommended thermal land pattern

The via diameter is should be approx. 0.3 mm with 1 oz. copper via barrel plating. Solder wicking inside the via resulting in voids during the solder process must be avoided. If the copper plating does not plug the vias, stencil print solder paste onto the printed circuit pad. This will supply enough solder paste to fill those vias and not starve the solder joints. The attachment process for exposed pad package is equivalent to standard surface mount packages. Figure 7 "Recommended solder mask openings" shows a recommend solder mask opening with respect to the

recommended 3 x 3 thermal via array. Because a large solder mask opening may result in a poor release, the opening should be subdivided as shown in Figure 7 For the nominal package standoff 0.1 mm, a stencil thickness of 5 to 8 mils should be considered.

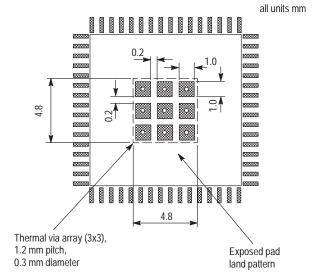


Figure 7. Recommended solder mask openings

For thermal system analysis and junction temperature calculation the thermal resistance parameters of the package is provided:

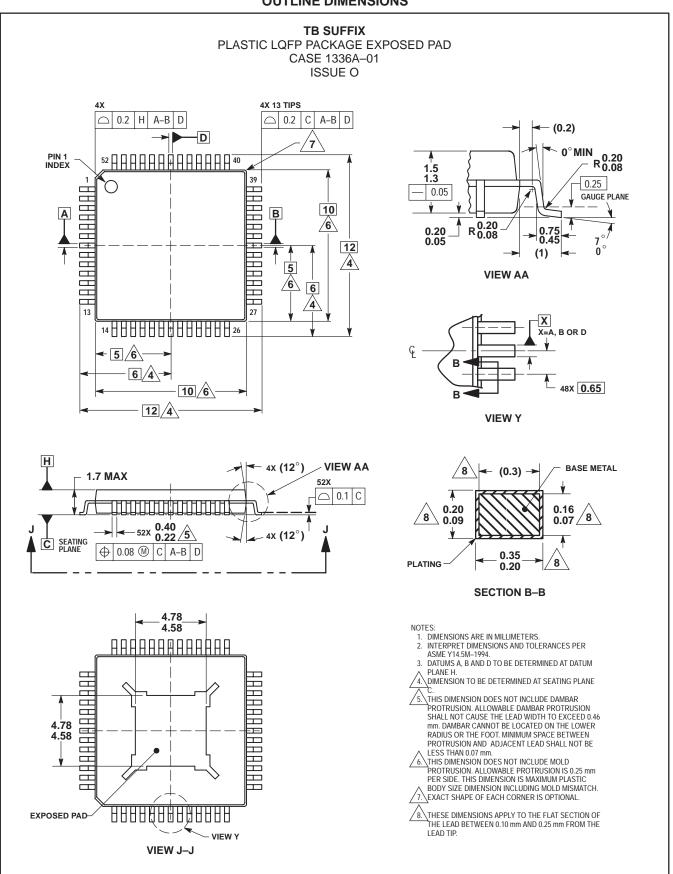
Table 8. Thermal Resistance<sup>a</sup>

Convection- LFPM	RTHJA <sup>b</sup> °C/W	RTHJA <sup>C</sup> °C/W	RTHJC °C/W	RTHJB <sup>d</sup> °C/W
Natural	20	48		
100	18	47	40	
200	17	46	4e 29f	16
400	16	43		
800	15	41		

- a. Applicable for a 3 x 3 thermal via array
- b. Junction to ambient, four conductor layer test board (2S2P), per JES51-7 and JESD 51-5
- c. Junction to ambient, single layer test board, per JESD51-3
- d. Junction to board, four conductor layer test board (2S2P) per JESD 51-8
- e. Junction to exposed pad
- f. Junction to top of package

It is recommended that users employ thermal modeling analysis to assist in applying the general recommendations to their particular application. The exposed pad of the MC100ES6220 package does not have an electrical low impedance path to the substrate of the integrated circuit and its terminals. The thermal land should be connected to GND through connection of internal board layers.

### **OUTLINE DIMENSIONS**



**NOTES** 

**NOTES** 

**NOTES** 

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